



# PJC7472B

## 60V N-Channel Enhancement Mode MOSFET

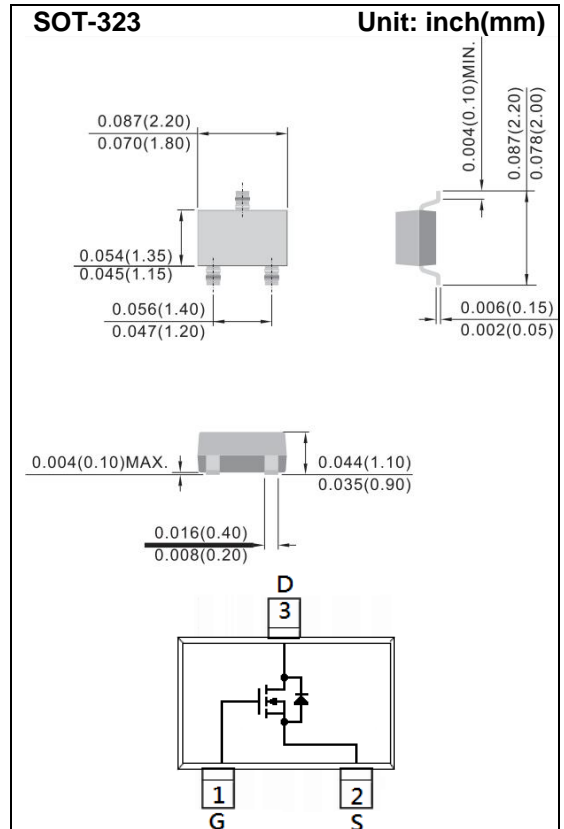
**Voltage** 60 V **Current** 250mA

### Features

- RDS(ON) , VGS@10V, ID@600mA<3Ω
- RDS(ON) , VGS@4.5V, ID@200mA<4Ω
- Advanced Trench Process Technology
- Specially Designed for Relay driver, Speed line drive, etc.
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

### Mechanical Data

- Case: SOT-323 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.00018 ounces, 0.005 grams
- Marking: C2B



## Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V <sub>DS</sub>	60	V
Gate-Source Voltage		V <sub>GS</sub>	+30	V
Continuous Drain Current		I <sub>D</sub>	250	mA
Pulsed Drain Current		I <sub>DM</sub>	1000	mA
Power Dissipation	T <sub>A</sub> =25°C	P <sub>D</sub>	350	mW
	Derate above 25°C		4	mW/°C
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55~150	°C
Typical Thermal resistance		R <sub>θJA</sub>	357	°C/W
- Junction to Ambient <sup>(Note 3)</sup>				



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## Electrical Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
<b>Static</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=250\mu A$	60	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	1.0	1.8	2.5	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=600mA$	-	1.3	3	$\Omega$
		$V_{GS}=4.5V, I_D=200mA$	-	1.7	4	
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=60V, V_{GS}=0V$	-	-	1	$\mu A$
Gate-Source Leakage Current	$I_{GSS}$	$V_{GS}=\pm 30V, V_{DS}=0V$	-	-	$\pm 100$	nA
<b>Dynamic</b> (Note 4)						
Total Gate Charge	$Q_g$	$V_{DS}=15V, I_D=600mA,$ $V_{GS}=4.5V$	-	0.82	-	nC
Gate-Source Charge	$Q_{gs}$		-	0.53	-	
Gate-Drain Charge	$Q_{gd}$		-	0.22	-	
Input Capacitance	$C_{iss}$	$V_{DS}=25V, V_{GS}=0V,$ $f=1.0MHz$	-	34	-	$\mu F$
Output Capacitance	$C_{oss}$		-	11	-	
Reverse Transfer Capacitance	$C_{rss}$		-	3.0	-	
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=10V, I_D=600mA,$ $V_{GS}=10V,$ $R_G=6\Omega$ (Note 1,2)	-	2.7	-	ns
Turn-On Rise Time	$t_r$		-	21	-	
Turn-Off Delay Time	$t_{d(off)}$		-	3.8	-	
Turn-Off Fall Time	$t_f$		-	18	-	
<b>Drain-Source Diode</b>						
Maximum Continuous Drain-Source Diode Forward Current	$I_S$	---	-	-	500	mA
Diode Forward Voltage	$V_{SD}$	$I_S=500mA, V_{GS}=0V$	-	0.9	1.5	V

**NOTES :**

1. Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3.  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. mounted on a 1 inch square pad of copper
4. Guaranteed by design, not subject to production testing



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## TYPICAL CHARACTERISTIC CURVES

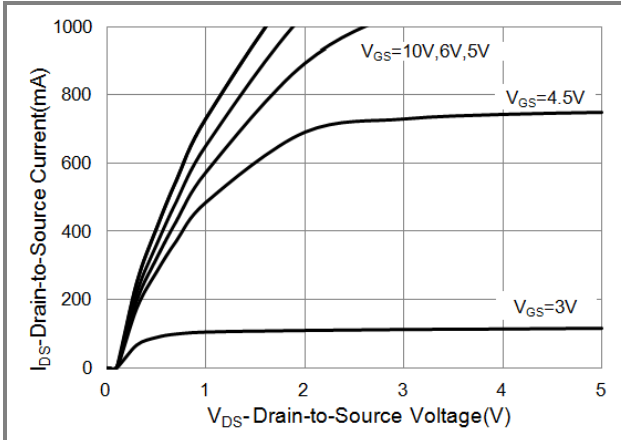


Fig.1 On-Region Characteristics

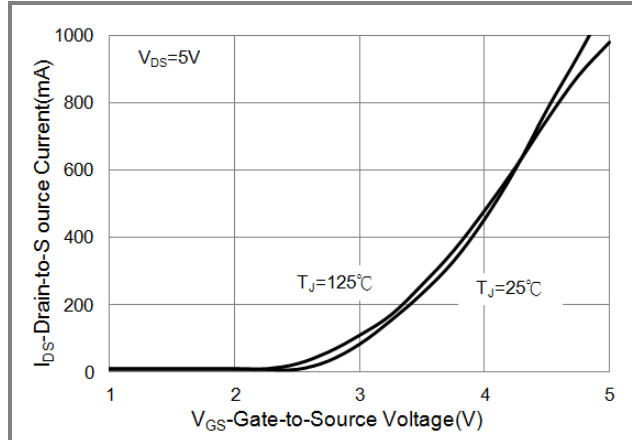


Fig.2 Transfer Characteristics

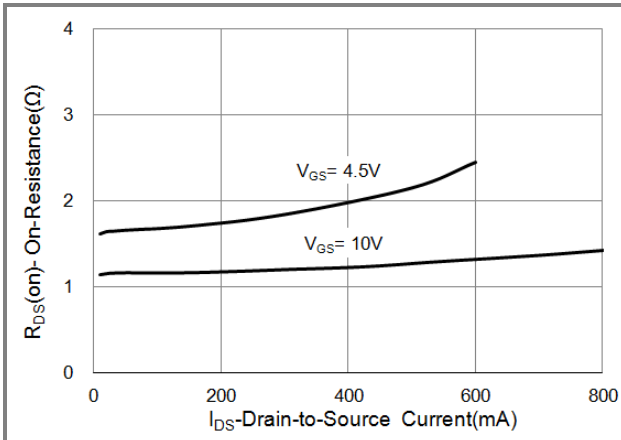


Fig.3 On-Resistance vs. Drain Current

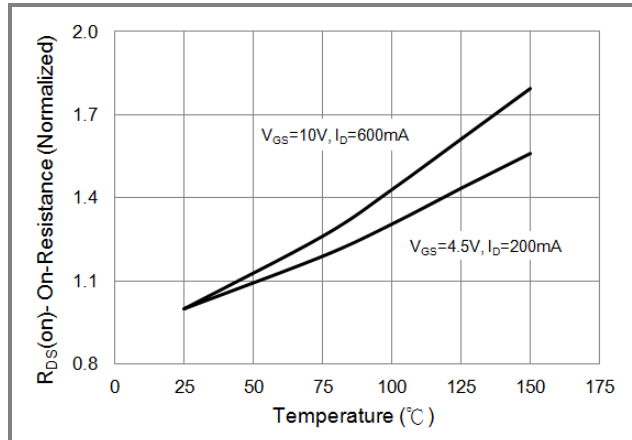


Fig.4 On-Resistance vs. Junction temperature

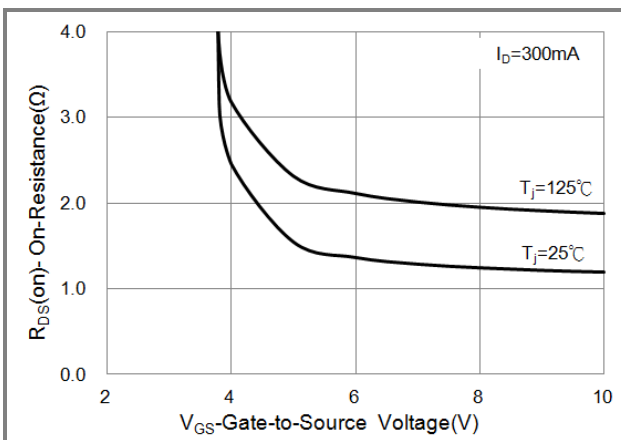


Fig.5 On-Resistance Variation with VGS.

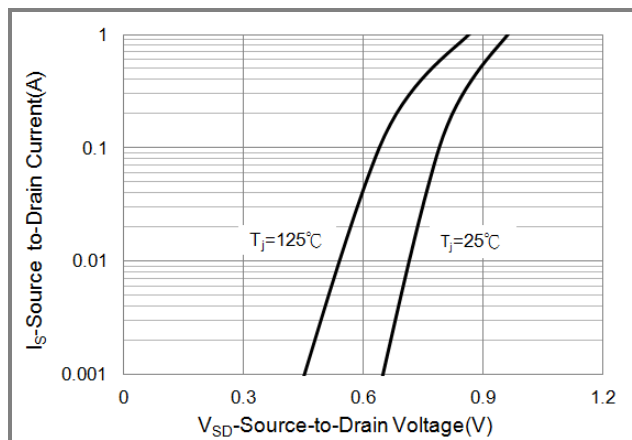


Fig.6 Body Diode Characteristics



# PJC7472B

## TYPICAL CHARACTERISTIC CURVES

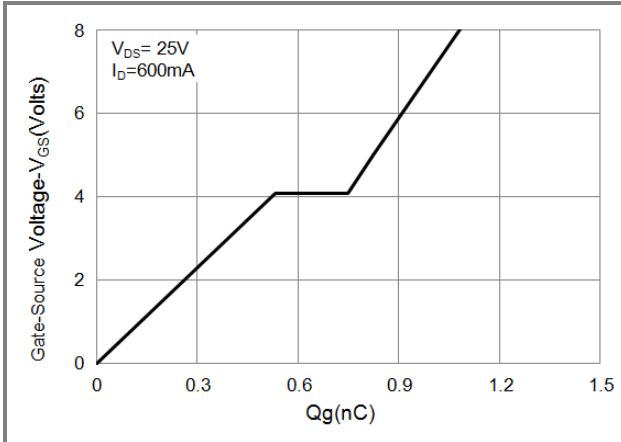


Fig.7 Gate-Charge Characteristics

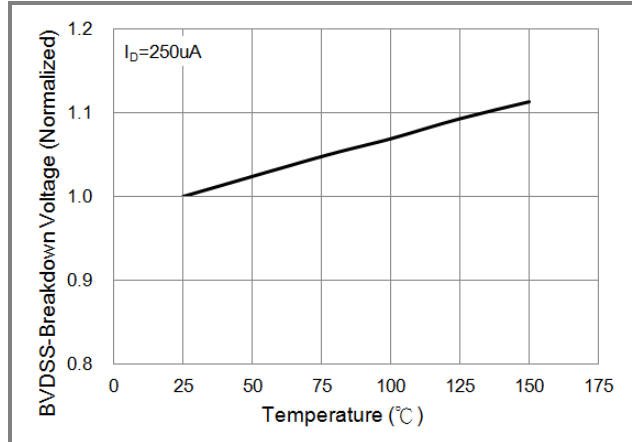


Fig.8 Breakdown Voltage Variation vs. Temperature

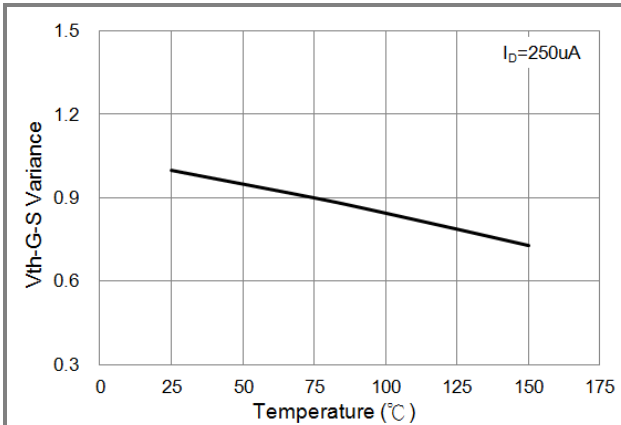


Fig.9 Threshold Voltage Variation with Temperature.

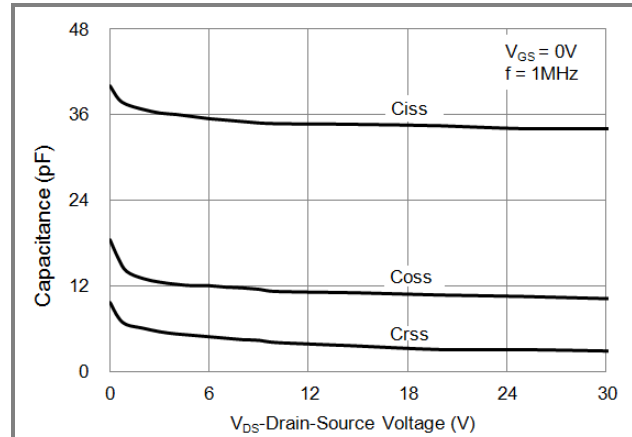


Fig.10 Capacitance vs. Drain-Source Voltage.

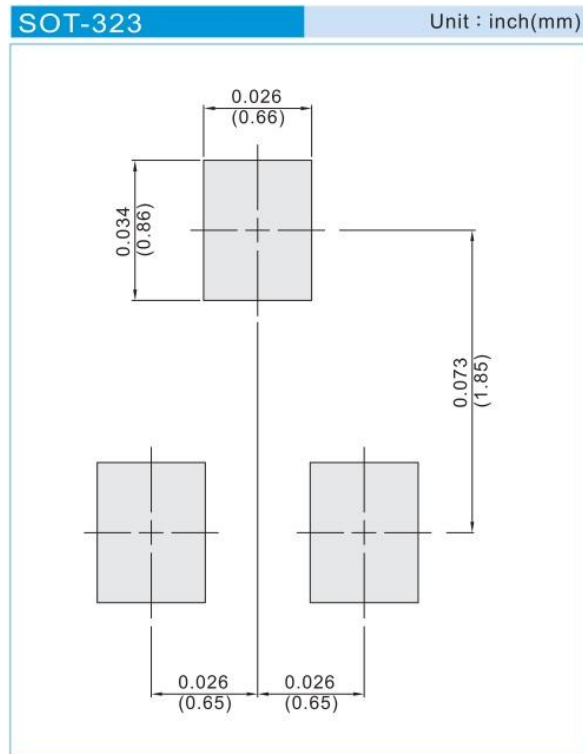


# PJC7472B

## PART NO PACKING CODE VERSION

PART NO PACKING CODE	Package Type	Packing type	Marking	Version
PJC7472B_R1_00001	SOT-323	3K pcs / 7" reel	C2B	Halogen free
PJC7472B_R2_00001	SOT-323	12K pcs / 13" reel	C2B	Halogen free

## MOUNTING PAD LAYOUT





## PJC7472B

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